5V ECL Quad 4-Input OR/NOR Gate

The MC10E/100E101 is a quad 4-input OR/NOR gate. The 100 Series contains temperature compensation.

- 500 ps Max. Propagation Delay
- PECL Mode Operating Range: V_{CC} = 4.2 V to 5.7 V with V_{EE} = 0 V
- NECL Mode Operating Range: V_{CC} = 0 V with V_{EE} = -4.2 V to -5.7 V
- Internal Input 50 KΩ Pulldown Resistors
- ESD Protection: Human Body Model; > 2 KV, Machine Model; > 200 V
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity Level 1
 For Additional Information, see Application Note AND8003/D
- Flammability Rating: UL 94 V-0 @ 0.125 in, Oxygen Index: 28 to 34
- Transistor Count = 115 devices

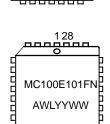


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PLCC-28 FN SUFFIX CASE 776



MARKING

DIAGRAMS

MC10E101FN

AWLYYWW

A = Assembly Location

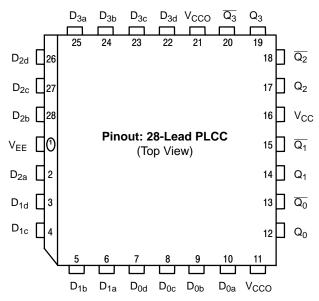
WL = Wafer Lot YY = Year WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping [†]
MC10E101FN	PLCC-28	37 Units/Rail
MC10E101FNR2	PLCC-28	500 Units/Reel
MC100E101FN	PLCC-28	37 Units/Rail
MC100E101FNR2	PLCC-28	500 Units/Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

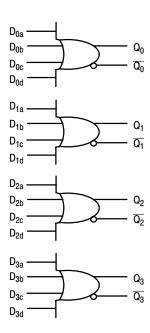
LOGIC DIAGRAM AND PINOUT ASSIGNMENT



 $^{^{\}ast}$ All V_{CC} and V_{CCO} pins are tied together on the die.

Warning: All V_{CC} , V_{CCO_i} and V_{EE} pins must be externally connected to Power Supply to guarantee proper operation.

LOGIC DIAGRAM



PIN DESCRIPTION

PIN	FUNCTION
D _{0a} – D _{3d}	ECL Data Inputs
$Q_0 - Q3$, $\overline{Q_0} - \overline{Q_3}$	ECL Differential Outputs
V_{CC}, V_{CCO}	Positive Supply
V _{EE}	Negative Supply

MAXIMUM RATINGS (Note 1)

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V _{CC}	PECL Mode Power Supply	V _{EE} = 0 V		8	V
Vi	PECL Mode Input Voltage NECL Mode Input Voltage	V _{EE} = 0 V V _{CC} = 0 V	$\begin{array}{c} V_{I} \leq V_{CC} \\ V_{I} \geq V_{EE} \end{array}$	6 -6	V V
I _{out}	Output Current	Continuous Surge		50 100	mA mA
T _A	Operating Temperature Range			0 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θ_{JA}	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	28 PLCC 28 PLCC	63.5 43.5	°C/W
$\theta_{\sf JC}$	Thermal Resistance (Junction to Case)	Standard Board	28 PLCC	22 to 26	°C/W
T _{sol}	Wave Solder	<2 to 3 sec @ 248°C		265	°C

^{1.} Maximum Ratings are those values beyond which device damage may occur.

10E SERIES PECL DC CHARACTERISTICS V_{CCx}= 5.0 V; V_{EE}= 0.0 V (Note 2)

			0°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		30	36		30	36		30	36	mA
V _{OH}	Output HIGH Voltage (Note 3)	3980	4070	4160	4020	4105	4190	4090	4185	4280	mV
V _{OL}	Output LOW Voltage (Note 3)	3050	3210	3370	3050	3210	3370	3050	3227	3405	mV
V _{IH}	Input HIGH Voltage	3830	3995	4160	3870	4030	4190	3940	4110	4280	mV
V _{IL}	Input LOW Voltage	3050	3285	3520	3050	3285	3520	3050	3302	3555	mV
I _{IH}	Input HIGH Current			150			150			150	μΑ
I _{IL}	Input LOW Current	0.5	0.3		0.5	0.25		0.3	0.2		μΑ

Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

- 2. Input and output parameters vary 1:1 with V_{CC} . \dot{V}_{EE} can vary -0.46 V / +0.06 V. 3. Outputs are terminated through a 50 ohm resistor to V_{CC} 2 volts.

10E SERIES NECL DC CHARACTERISTICS V_{CCx} = 0.0 V; V_{EE} = -5.0 V (Note 4)

			0°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		30	36		30	36		30	36	mA
V _{OH}	Output HIGH Voltage (Note 5)	-1020	-930	-840	-980	-895	-810	-910	-815	-720	mV
V _{OL}	Output LOW Voltage (Note 5)	-1950	-1790	-1630	-1950	-1790	-1630	-1950	-1773	-1595	mV
V _{IH}	Input HIGH Voltage	-1170	-1005	-840	-1130	-970	-810	-1060	-890	-720	mV
V _{IL}	Input LOW Voltage	-1950	-1715	-1480	-1950	-1715	-1480	-1950	-1698	-1445	mV
I _{IH}	Input HIGH Current			150			150			150	μΑ
I _{IL}	Input LOW Current	0.5	0.3		0.5	0.065		0.3	0.2		μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

- 4. Input and output parameters vary 1:1 with V_{CC} . \dot{V}_{EE} can vary -0.46 V / +0.06 V. 5. Outputs are terminated through a 50 ohm resistor to V_{CC} 2 volts.

100E SERIES PECL DC CHARACTERISTICS $V_{CCx} = 5.0 \text{ V}$; $V_{EE} = 0.0 \text{ V}$ (Note 6)

			0°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		30	36		30	36		35	42	mA
V _{OH}	Output HIGH Voltage (Note 7)	3975	4050	4120	3975	4050	4120	3975	4050	4120	mV
V _{OL}	Output LOW Voltage (Note 7)	3190	3295	3380	3190	3255	3380	3190	3260	3380	mV
V _{IH}	Input HIGH Voltage	3835	3975	4120	3835	3975	4120	3835	3975	4120	mV
V _{IL}	Input LOW Voltage	3190	3355	3525	3190	3355	3525	3190	3355	3525	mV
I _{IH}	Input HIGH Current			150			150			150	μΑ
I _{IL}	Input LOW Current	0.5	0.3		0.5	0.25		0.5	0.2		μΑ

Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

- 6. Input and output parameters vary 1:1 with V_{CC}. \dot{V}_{EE} can vary –0.46 V / +0.8 V. 7. Outputs are terminated through a 50 ohm resistor to V_{CC} 2 volts.

100E SERIES NECL DC CHARACTERISTICS V_{CCx} = 0.0 V; V_{EE} = -5.0 V (Note 8)

			0°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		30	36		30	36		35	42	mA
V _{OH}	Output HIGH Voltage (Note 9)	-1025	-950	-880	-1025	-950	-880	-1025	-950	-880	mV
V_{OL}	Output LOW Voltage (Note 9)	-1810	-1705	-1620	-1810	-1745	-1620	-1810	-1740	-1620	mV
V_{IH}	Input HIGH Voltage	-1165	-1025	-880	-1165	-1025	-880	-1165	-1025	-880	mV
V _{IL}	Input LOW Voltage	-1810	-1645	-1475	-1810	-1645	-1475	-1810	-1645	-1475	mV
I _{IH}	Input HIGH Current			150			150			150	μΑ
I _{IL}	Input LOW Current	0.5	0.3		0.5	0.25		0.5	0.2		μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

- 8. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary -0.46 V / +0.8 V. 9. Outputs are terminated through a 50 ohm resistor to V_{CC} 2 volts.

AC CHARACTERISTICS V_{CCx} = 5.0 V; V_{EE} = 0.0 V or V_{CCx} = 0.0 V; V_{EE} = -5.0 V (Note 8)

				0°C			25°C			85°C		
Symbol	Characteristic		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f _{MAX}	Maximum Toggle Frequency			700			700			700		MHz
t _{PLH} t _{PHL}	Propagation Delay to Output	D to Q	200	350	500	200	350	500	200	350	500	ps
t _{SKEW}	Within-Device Skew (Note 11) Within-Gate Skew (Note 12)			50 25			50 25			50 25		ps
t _{JITTER}	Random Clock Jitter (RMS)			< 1			< 1			< 1		ps
t _r	Rise/Fall Time (20 - 80%)		300	380	575	300	380	575	300	380	575	ps

NOTE: Devices are designed to meet the AC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

^{10.10} Series: V_{EE} can vary –0.46 V / +0.06 V.
100 Series: V_{EE} can vary –0.46 V / +0.8 V.
11. Within-device skew is defined as identical transitions on similar paths through a device.

^{12.} Within-gate skew is defined as the variation in propagation delays of a gate when driven from its different inputs.

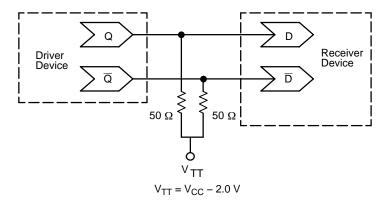


Figure 1. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020 – Termination of ECL Logic Devices.)

Resource Reference of Application Notes

AN1404 - ECLinPS Circuit Performance at Non–Standard V_{IH} Levels

AN1405 - ECL Clock Distribution Techniques

AN1406 - Designing with PECL (ECL at +5.0 V)

AN1503 - ECLinPS I/O SPICE Modeling Kit

AN1504 - Metastability and the ECLinPS Family

AN1568 - Interfacing Between LVDS and ECL

AN1596 - ECLinPS Lite Translator ELT Family SPICE I/O Model Kit

AN1650 - Using Wire-OR Ties in ECLinPS Designs

AND8001 - The ECL Translator Guide

AND8001 - Odd Number Counters Design

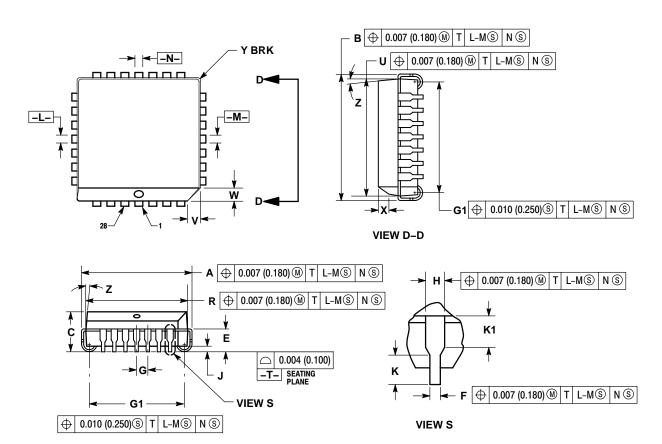
AND8002 - Marking and Date Codes

AND8020 - Termination of ECL Logic Devices

PACKAGE DIMENSIONS

PLCC-28 **FN SUFFIX**

PLASTIC PLCC PACKAGE CASE 776-02 **ISSUE E**



NOTES:

- IOTES:

 1. DATUMS -L-, -M-, AND -N- DETERMINED
 WHERE TOP OF LEAD SHOULDER EXITS
 PLASTIC BODY AT MOLD PARTING LINE.

 2. DIMENSION G1, TRUE POSITION TO BE
 MEASURED AT DATUM -T-, SEATING PLANE.

 3. DIMENSIONS R AND U DO NOT INCLUDE
- MOLD FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE. 4. DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982. 5. CONTROLLING DIMENSION: INCH.
- 6. THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE
- PLASTIC BODY.
 7. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

	INC	HES	MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.485	0.495	12.32	12.57
В	0.485	0.495	12.32	12.57
С	0.165	0.180	4.20	4.57
E	0.090	0.110	2.29	2.79
F	0.013	0.019	0.33	0.48
G	0.050	BSC	1.27	BSC
Н	0.026	0.032	0.66	0.81
J	0.020		0.51	
K	0.025		0.64	
R	0.450	0.456	11.43	11.58
U	0.450	0.456	11.43	11.58
٧	0.042	0.048	1.07	1.21
W	0.042	0.048	1.07	1.21
X	0.042	0.056	1.07	1.42
Υ		0.020		0.50
Z	2 °	10°	2°	10°
G1	0.410	0.430	10.42	10.92
K1	0.040		1.02	

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